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Comparative study of Au/Ti, Au/V and Au/Zr films oxygen gettering ability

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Abstract — In this work, thermal diffusion of titanium, vanadium and zirconium

through a thin capping gold layer has been investigated and compared in terms of

oxygen gettering ability after activation at low temperature. The films were

characterized by means of sheet resistance measurements, high resolution Scanning

Electron Microscopy, Ion Beam Etching coupled with Secondary Ions Mass

Spectrometry, X-ray diffraction, X-ray photoelectron spectrometry and mechanical

stress measurements. Results show that, among investigated bilayers, gold/zirconium

system is the best candidate to get low temperature getter film as its activation

temperature is below 200 °C for 1 hour annealing time.

Keywords: getter, diffusion, transition metals, vacuum packaging

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